



ZXMP2120E5

Product Summary

| V _(BR) dss | Rds(on) | I _D T _A = +25°C |
|-----------------------|-----------------------------|--|
| -200V | 28Ω @ V _{GS} = 10V | -122mA |

Description

This new generation trench MOSFET features a unique structure combining the benefits of low on-resistance and fast switching, making it ideal for high-efficiency power management applications.

Applications

 Active Clamping of Primary Side MOSFETs in 48 Volt DC-DC Converters

200V P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

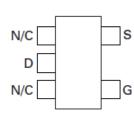
- High Voltage
- Low On-Resistance
- Fast Switching Speed
- Low Gate Drive
- Low Threshold
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

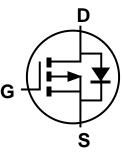
- Case: SOT25
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish @3
- Weight: 0.016 grams (Approximate)



Top View



Pin Out - Top



Equivalent Circuit

Ordering Information (Note 4)

| ZXMP2120E5TA P120 7 8 3.000 | Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-----------------------------|--------------|---------|--------------------|-----------------|-------------------|
| | ZXMP2120E5TA | P120 | 7 | 8 | 3,000 |

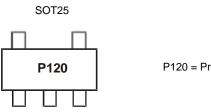
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



P120 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|------------------|-------|------|
| Drain-Source Voltage | V _{DSS} | -200 | V |
| Gate-Source Voltage | V _{GSS} | ±20 | V |
| Continuous Drain Current (V _{GS} = 10V; T _A = +25°C) (Note 5) | ID | -122 | mA |
| Pulsed Drain Current (Note 6) | I _{DM} | -0.7 | A |
| Pulsed Source Current (Body Diode) (Note 6) | I _{SM} | -0.7 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------------|
| Power Dissipation at $T_A = +25^{\circ}C$ (Note 5) Linear Derating Factor | PD | 0.75 6 | W mW/°C |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{θJA} | 167 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|------|-----|-------------|------|---|--|
| OFF CHARACTERISTICS | | | | | | · | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -200 | - | - | V | $V_{GS} = 0V, I_D = -1mA$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | - | - | -10 -100 | μA | $V_{DS} = -200V, V_{GS} = 0V$ $V_{DS} = -160V, V_{GS} = 0V, T = +125^{\circ}C$ | |
| Gate-Source Leakage | IGSS | - | - | 20 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -1.5 | - | -3.5 | V | $V_{DS} = V_{GS}$, $I_D = -1mA$ | |
| Static Drain-Source On-Resistance (Note 7) | R _{DS(ON)} | - | - | 28 | Ω | V _{GS} = -10V, I _D = -150mA | |
| Forward Transconductance (Notes 7 & 8) | g fs | 50 | - | - | mS | $V_{DS} = -25V, I_D = -150mA$ $V_{DS} = -25V, V_{GS} = -10V$ | |
| On-State Drain Current (Note 7) | I _{D(ON)} | -300 | - | - | mA | | |
| DYNAMIC CHARACTERISTICS | | | | | | | |
| Input Capacitance (Note 8) | Ciss | - | - | 100 | pF | V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz | |
| Output Capacitance (Note 8) | Coss | - | - | 25 | pF | | |
| Reverse Transfer Capacitance (Note 8) | Crss | - | - | 7 | pF | | |
| Turn-On Delay Time (Notes 8 & 9) | t _{D(ON)} | - | - | 7 | ns | V _{DD} = -25V, I _D = -150mA | |
| Turn-On Rise Time (Notes 8 & 9) | t _R | - | - | 15 | ns | | |
| Turn-Off Delay Time (Notes 8 & 9) | t _{D(OFF)} | - | - | 12 | ns | | |
| Turn-Off Fall Time (Notes 8 & 9) | t _F | - | - | 15 | ns | 1 | |

6. Repetitive rating - pulse width limited by maximum junction temperature. Refer to Transient Thermal Impedance graph. 7. Measured under pulsed conditions. Pulse width $\leq 300 \mu$ s. Duty cycle $\leq 2\%$.

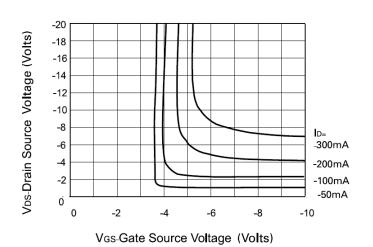
8. Sample test.

Switching characteristics are independent of operating junction temperature.

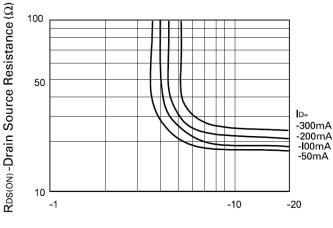


VGS I_{D(On)} -On-State Drain Current (Amps) /-10V -8V -0.6 -7V -6V -0.4 -5V -0.2 -4**.**5V -4V -3,5V 0 -20 -40 -60 -80 -100 VDs - Drain Source Voltage (Volts)



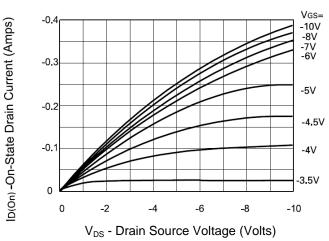


Voltage Saturation Characteristics

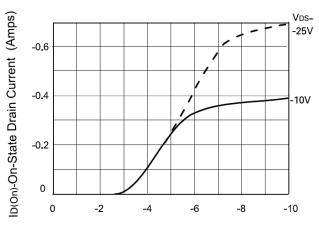


VGS-Gate Source Voltage (Volts)

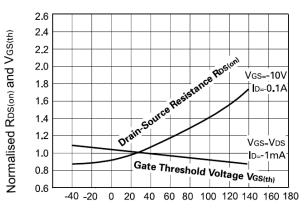
On-resistance vs gate-source voltage



Saturation Characteristics



Vgs-Gate Source Voltage (Volts)



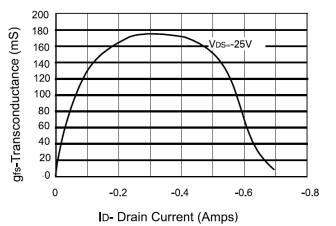
T-Temperature (°C)

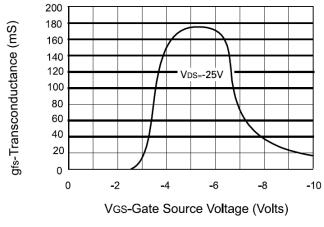
Normalised RDS(on) and VGS(th) vs Temperature



ZXMP2120E5

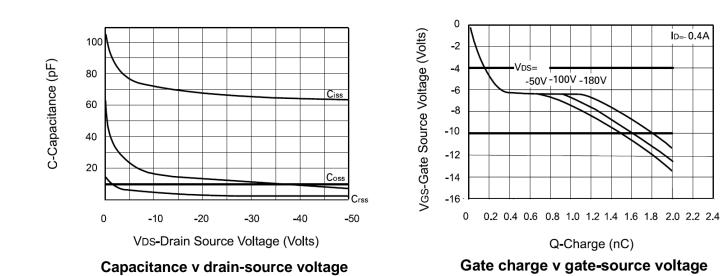
D= 0.4A





Transconductance v drain current

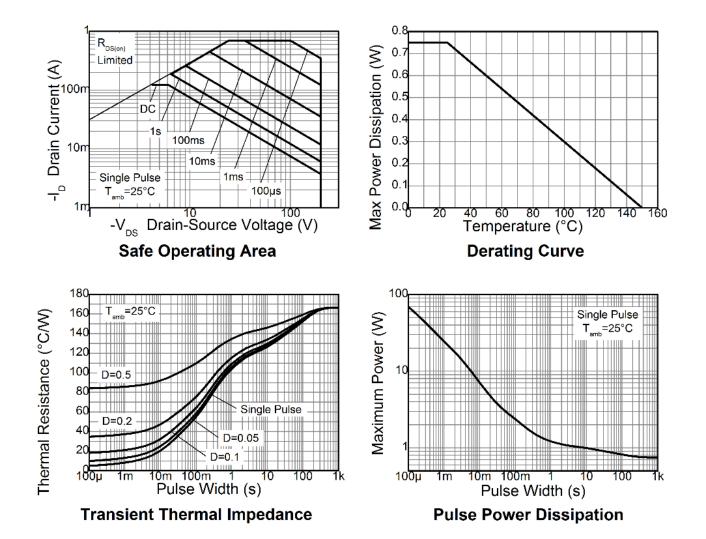




ZXMP2120E5 Document number: DS33600 Rev. 3 - 2



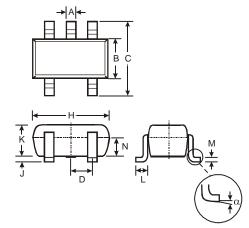
Thermal Characteristics





Package Outline Dimensions

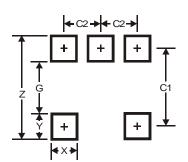
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT25 | | | | | |
|-------|----------------------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.35 | 0.50 | 0.38 | | |
| В | 1.50 | 1.70 | 1.60 | | |
| С | 2.70 | 3.00 | 2.80 | | |
| D | - | - | 0.95 | | |
| Н | 2.90 | 3.10 | 3.00 | | |
| J | 0.013 | 0.10 | 0.05 | | |
| κ | 1.00 | 1.30 | 1.10 | | |
| L | 0.35 | 0.55 | 0.40 | | |
| Μ | 0.10 | 0.20 | 0.15 | | |
| Ν | 0.70 | 0.80 | 0.75 | | |
| α | 0° | 8° | - | | |
| All D | All Dimensions in mm | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | SOT25 |
|------------|-------|
| Z | 3.20 |
| G | 1.60 |
| Х | 0.55 |
| Y | 0.80 |
| C1 | 2.40 |
| C2 | 0.95 |



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